

## COMPLEMENTARY NPN/PNP PRE-BIASED SMALL SIGNAL SOT-363 DUAL SURFACE MOUNT TRANSISTOR

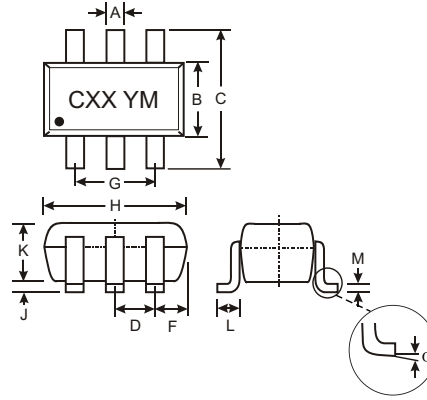
NEW PRODUCT

### Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors

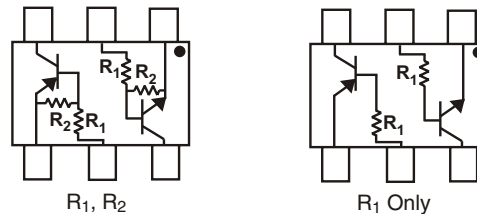
### Mechanical Data

- Case: SOT-363, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 4)
- Weight: 0.006 grams (approx.)
- Ordering Information (See Page 3)



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
$\alpha$	0°	8°
All Dimensions in mm		

P/N	R1	R2	MARKING
DCX124EU	22K $\Omega$	22K $\Omega$	C17
DCX144EU	47K $\Omega$	47K $\Omega$	C20
DCX114YU	10K $\Omega$	47K $\Omega$	C14
DCX123JU	2.2K $\Omega$	47K $\Omega$	C06
DCX114EU	10K $\Omega$	10K $\Omega$	C13
DCX143TU	4.7K $\Omega$	-	C07
DCX114TU	10K $\Omega$	-	C12



SCHEMATIC DIAGRAM

### Maximum Ratings NPN Section @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	V <sub>CC</sub>	50	V
Input Voltage, (2) to (1)	V <sub>IN</sub>	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5 V <sub>max</sub> -5 V <sub>max</sub>	V
Output Current	I <sub>O</sub>	30 30 70 100 50 100 100	mA
Output Current	I <sub>C</sub> (Max)	100	mA
Power Dissipation (Total)	P <sub>d</sub>	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R <sub>θJA</sub>	625	°C/W
Operating and Storage and Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

- Note:
1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
  2. 150mW per element must not be exceeded.

**Maximum Ratings PNP Section** @  $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	$V_{CC}$	50	V
Input Voltage, (2) to (1) DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX114TU	$V_{IN}$	+10 to -40 +10 to -40 +6 to -40 +5 to -12 +10 to -40 +5 $V_{max}$ +5 $V_{max}$	V
Output Current DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU DCX143TU DCX114TU	$I_O$	-30 -30 -70 -100 -50 -100 -100	mA
Output Current All	$I_C$ (Max)	-100	mA
Power Dissipation (Total)	$P_d$	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Operating and Storage and Temperature Range	$T_j, T_{STG}$	-55 to +150	$^\circ\text{C}$

Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.  
2. 150mW per element must not be exceeded.

**Electrical Characteristics NPN Section** @  $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic (DCX143TU & DCX114TU only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	50	—	—	V	$I_C = 50\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	50	—	—	V	$I_C = 1\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	5	—	—	V	$I_E = 50\mu\text{A}$
Collector Cutoff Current	$I_{CBO}$	—	—	0.5	$\mu\text{A}$	$V_{CB} = 50\text{V}$
Emitter Cutoff Current	$I_{EBO}$	—	—	0.5	$\mu\text{A}$	$V_{EB} = 4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	0.3	V	$I_C/I_B = 2.5\text{mA} / 0.25\text{mA}$ DCX143TU $I_C/I_B = 1\text{mA} / 0.1\text{mA}$ DCX114TU
DC Current Transfer Ratio	$h_{FE}$	100	250	600	—	$I_C = 1\text{mA}, V_{CE} = 5\text{V}$
Input Resistor ( $R_1$ ) Tolerance	$\Delta R_1$	-30	—	+30	%	—
Gain-Bandwidth Product*	$f_T$	—	250	—	MHz	$V_{CE} = 10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU	$V_{I(off)}$	0.5	1.1	—	V	$V_{CC} = 5\text{V}, I_O = 100\mu\text{A}$
		0.5	1.1	—		
Input Voltage DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU	$V_{I(on)}$	—	1.9	3.0	V	$V_O = 0.3, I_O = 5\text{mA}$ $V_O = 0.3, I_O = 2\text{mA}$ $V_O = 0.3, I_O = 1\text{mA}$ $V_O = 0.3, I_O = 5\text{mA}$ $V_O = 0.3, I_O = 10\text{mA}$
		—	1.9	3.0		
Output Voltage DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU	$V_{O(on)}$	—	0.1	0.3	V	$I_O/I_I = 10\text{mA} / 0.5\text{mA}$ $I_O/I_I = 10\text{mA} / 0.5\text{mA}$ $I_O/I_I = 5\text{mA} / 0.25\text{mA}$ $I_O/I_I = 5\text{mA} / 0.25\text{mA}$ $I_O/I_I = 10\text{mA} / 0.5\text{mA}$
Input Current DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU	$I_I$	—	—	0.36 0.18 0.88 3.6 0.88	mA	$V_I = 5\text{V}$
Output Current	$I_{O(off)}$	—	—	0.5	$\mu\text{A}$	$V_{CC} = 50\text{V}, V_I = 0\text{V}$
DC Current Gain DCX124EU DCX144EU DCX114YU DCX123JU DCX114EU	$G_I$	56 68 68 80 30	—	—	—	$V_O = 5\text{V}, I_O = 5\text{mA}$ $V_O = 5\text{V}, I_O = 5\text{mA}$ $V_O = 5\text{V}, I_O = 10\text{mA}$ $V_O = 5\text{V}, I_O = 10\text{mA}$ $V_O = 5\text{V}, I_O = 5\text{mA}$
Input Resistor ( $R_1$ ) Tolerance	$\Delta R_1$	-30	—	+30	%	—
Resistance Ratio Tolerance	$R_2/R_1$	-20	—	+20	%	—
Gain-Bandwidth Product*	$f_T$	—	250	—	MHz	$V_{CE} = 10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$

\* Transistor - For Reference Only

Electrical Characteristics PNP Section @  $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic (DCX143TU & DCX114TU only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-50	—	—	V	$I_C = -50\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	-50	—	—	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-5	—	—	V	$I_E = -50\mu\text{A}$
Collector Cutoff Current	$I_{CBO}$	—	—	-0.5	$\mu\text{A}$	$V_{CB} = -50\text{V}$
Emitter Cutoff Current	$I_{EBO}$	—	—	-0.5	$\mu\text{A}$	$V_{EB} = -4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	-0.3	V	$I_C/I_B = 2.5\text{mA} / 0.25\text{mA}$ DCX143TU $I_C/I_B = 1\text{mA} / 0.1\text{mA}$ DCX114TU
DC Current Transfer Ratio	$h_{FE}$	100	250	600	—	$I_C = -1\text{mA}, V_{CE} = -5\text{V}$
Input Resistor ( $R_1$ ) Tolerance	$\Delta R_1$	-30	—	+30	%	—
Gain-Bandwidth Product*	$f_T$	—	250	—	MHz	$V_{CE} = -10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
Input Voltage	$V_{I(off)}$	DCX124EU	-0.5	-1.1	—	V	$V_{CC} = -5\text{V}, I_O = -100\mu\text{A}$
		DCX144EU	-0.5	-1.1			
	$V_{I(on)}$	DCX114YU	-0.3	—	—	V	$V_O = -0.3, I_O = -5\text{mA}$
		DCX123JU	-0.5	—			
	$V_{I(on)}$	DCX114EU	-0.5	-1.1	—	V	$V_O = -0.3, I_O = -2\text{mA}$
		DCX124EU	—	-1.9			
	$V_{I(on)}$	DCX144EU	—	-1.9	—	V	$V_O = -0.3, I_O = -1\text{mA}$
		DCX114YU	—	-1.4			
	$V_{I(on)}$	DCX123JU	—	-1.1	—	V	$V_O = -0.3, I_O = -5\text{mA}$
		DCX114EU	—	-1.9			
Output Voltage	$V_{O(on)}$	DCX124EU	—	-0.1	-0.3	V	$I_O/I_I = -10\text{mA} / -0.5\text{mA}$
		DCX144EU	—	-0.1			
	$V_{O(on)}$	DCX114YU	—	-0.1	-0.3	V	$I_O/I_I = -10\text{mA} / -0.5\text{mA}$
		DCX123JU	—	-0.1			
	$V_{O(on)}$	DCX114EU	—	-0.1	-0.3	V	$I_O/I_I = -5\text{mA} / -0.25\text{mA}$
		DCX124EU	—	-0.1			
Input Current	$I_I$	DCX124EU	—	—	-0.36	mA	$V_I = -5\text{V}$
		DCX144EU	—	—	-0.18		
	$I_I$	DCX114YU	—	—	-0.88	mA	$V_I = -5\text{V}$
		DCX123JU	—	—	-3.6		
	$I_I$	DCX114EU	—	—	-0.88	mA	$V_I = -5\text{V}$
		DCX124EU	—	—	-0.88		
Output Current	$I_{O(off)}$	—	—	-0.5	$\mu\text{A}$	$V_{CC} = 50\text{V}, V_I = 0\text{V}$	
DC Current Gain	$G_I$	DCX124EU	56	—	—	—	$V_O = -5\text{V}, I_O = -5\text{mA}$
		DCX144EU	68	—	—		
	$G_I$	DCX114YU	68	—	—	—	$V_O = -5\text{V}, I_O = -5\text{mA}$
		DCX123JU	80	—	—		
	$G_I$	DCX114EU	30	—	—	—	$V_O = -5\text{V}, I_O = -10\text{mA}$
		DCX124EU	30	—	—		
Input Resistor ( $R_1$ ) Tolerance	$\Delta R_1$	-30	—	+30	%	—	
Resistance Ratio Tolerance	$R_2/R_1$	-20	—	+20	%	—	
Gain-Bandwidth Product*	$f_T$	—	250	—	MHz	$V_{CE} = -10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$	

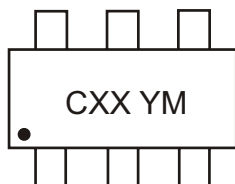
\* Transistor - For Reference Only

## Ordering Information (Note 3)

Device	Packaging	Shipping
DCX124EU-7	SOT-363	3000/Tape & Reel
DCX144EU-7	SOT-363	3000/Tape & Reel
DCX114YU-7	SOT-363	3000/Tape & Reel
DCX123JU-7	SOT-363	3000/Tape & Reel
DCX114EU-7	SOT-363	3000/Tape & Reel
DCX143TU-7	SOT-363	3000/Tape & Reel
DCX114TU-7	SOT-363	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



CXX = Product Type Marking Code  
 See Sheet 1 Diagrams  
 YM = Date Code Marking  
 Y = Year ex: N = 2002  
 M = Month ex: 9 = September

Date Code Key

<b>Year</b>	<b>2002</b>	<b>2003</b>	<b>2004</b>	<b>2005</b>	<b>2006</b>	<b>2007</b>	<b>2008</b>	<b>2009</b>
<b>Code</b>	N	P	R	S	T	U	V	W

<b>Month</b>	<b>Jan</b>	<b>Feb</b>	<b>March</b>	<b>Apr</b>	<b>May</b>	<b>Jun</b>	<b>Jul</b>	<b>Aug</b>	<b>Sep</b>	<b>Oct</b>	<b>Nov</b>	<b>Dec</b>
<b>Code</b>	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DCX123JU  
PNP SECTION

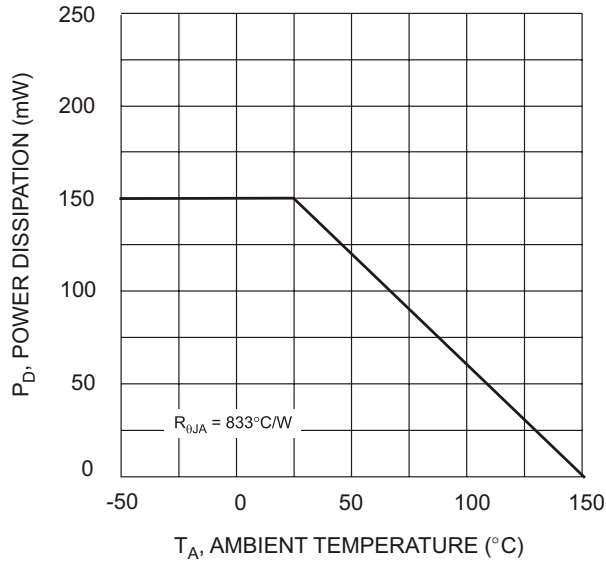


Fig. 1 Derating Curve

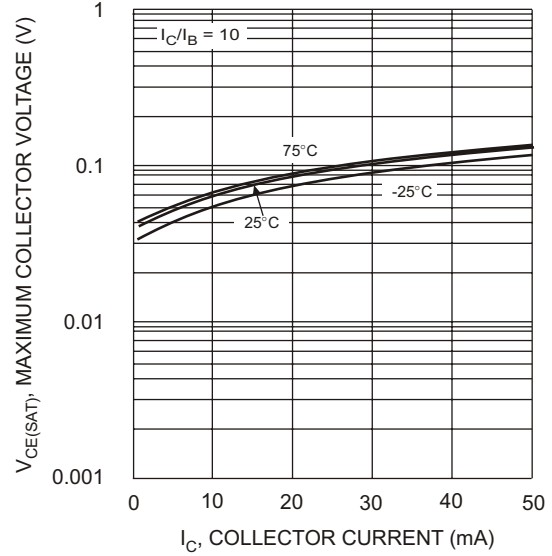


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

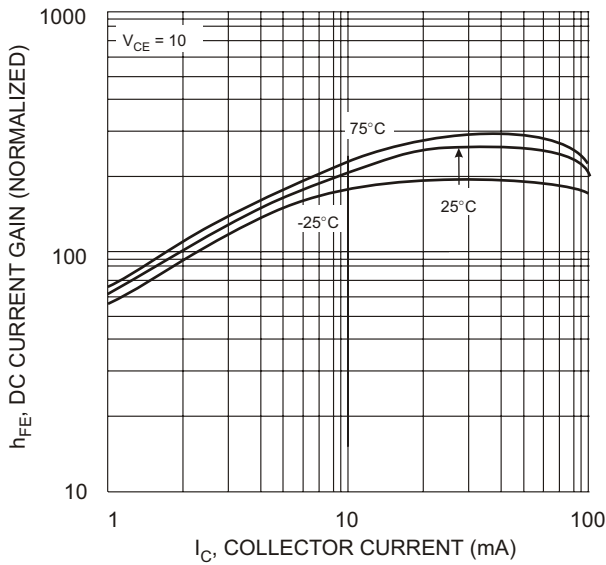


Fig. 3 DC Current Gain

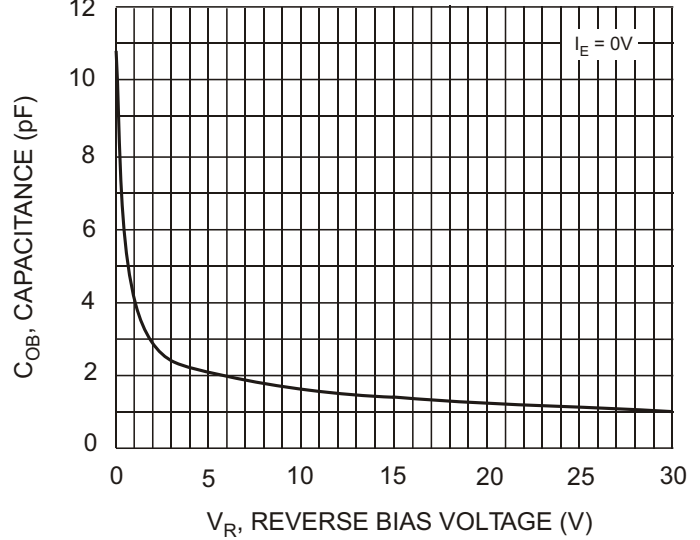


Fig. 4 Output Capacitance

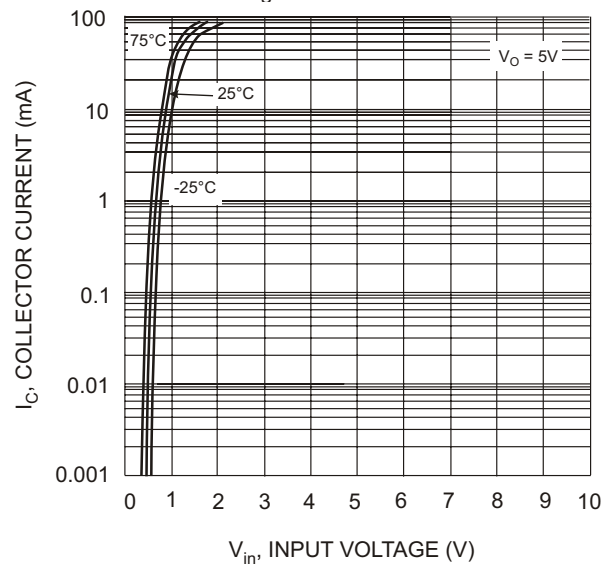


Fig. 5 Collector Current Vs. Input Voltage

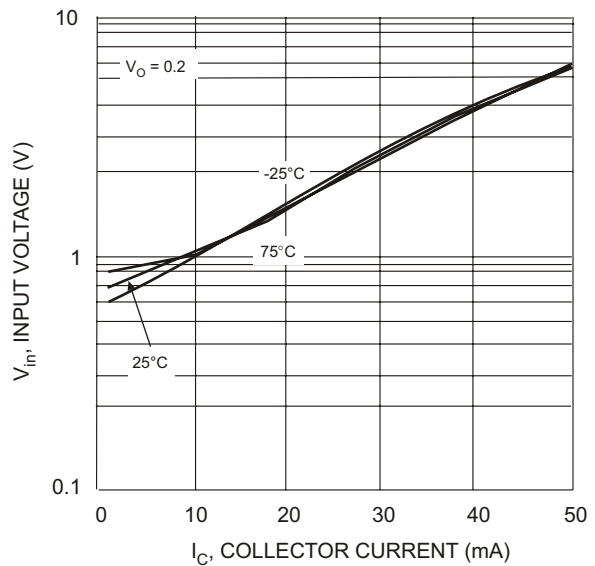


Fig. 6 Input Voltage vs. Collector Current

TYPICAL CURVES - DCX123JU  
NPN SECTION

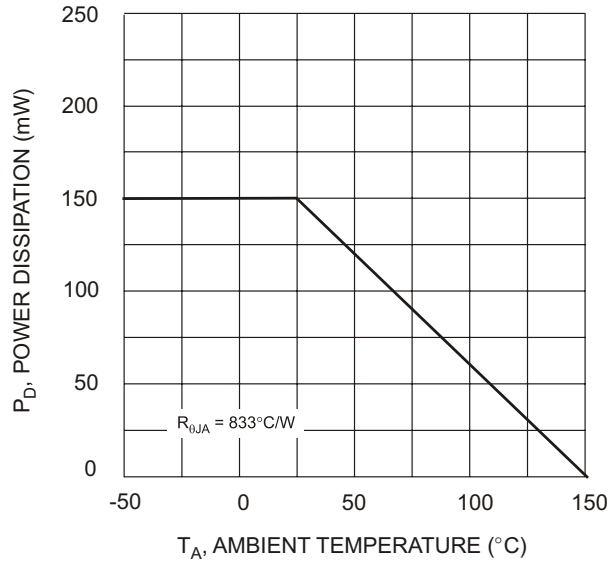


Fig. 1 Derating Curve

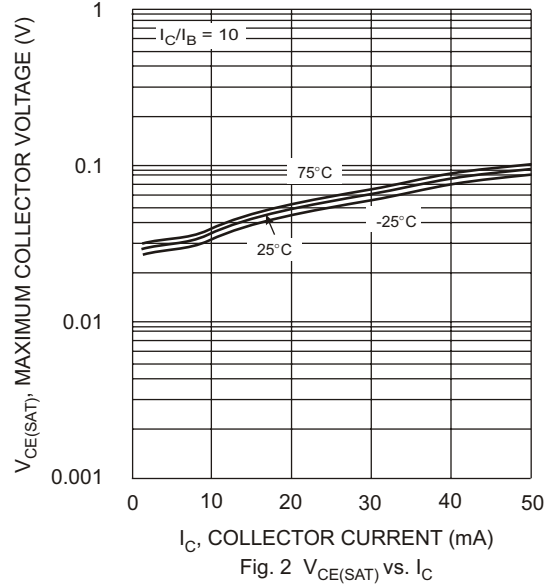


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

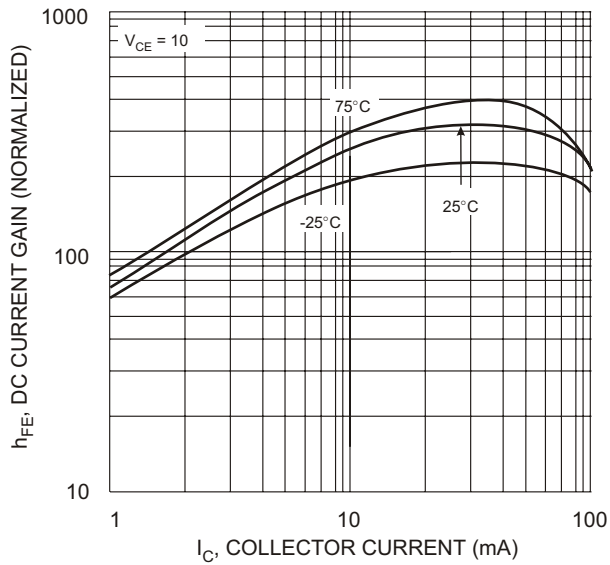


Fig. 3 DC Current Gain

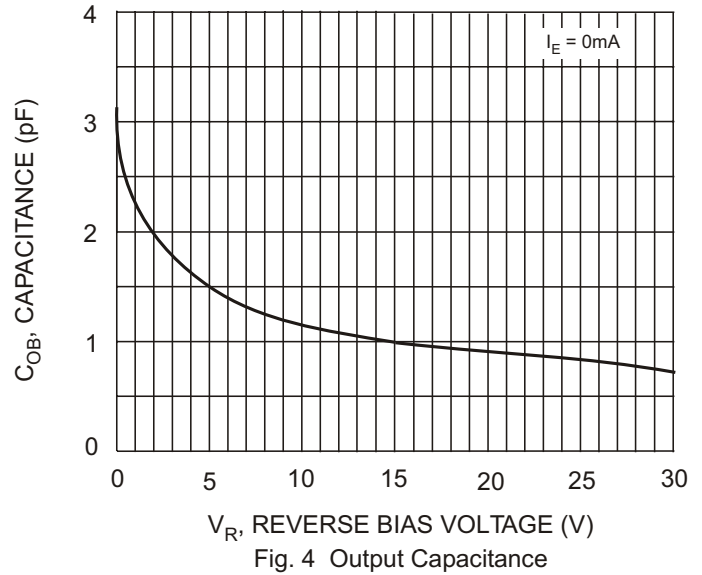


Fig. 4 Output Capacitance

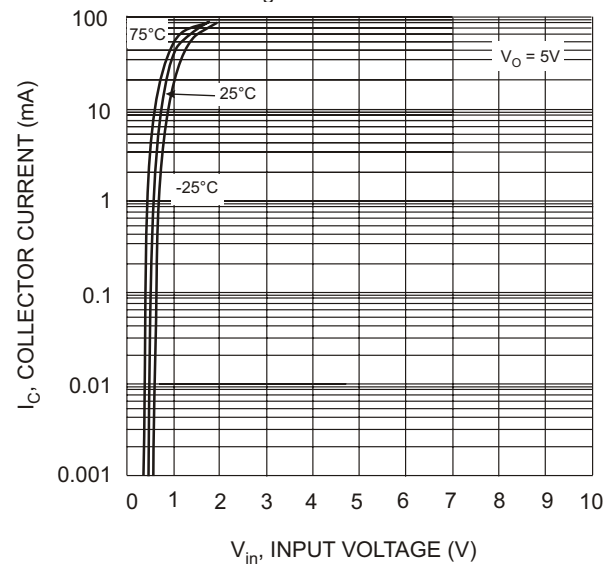


Fig. 5 Collector Current Vs. Input Voltage

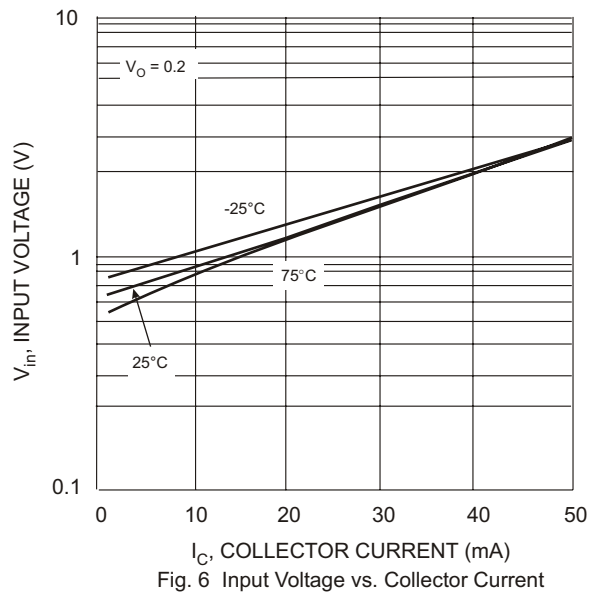


Fig. 6 Input Voltage vs. Collector Current

TYPICAL CURVES - DCX114TU  
PNP SECTION

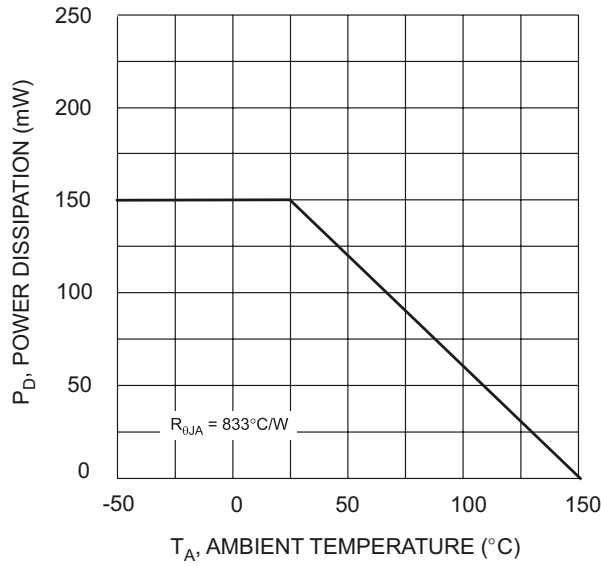


Fig. 1 Derating Curve

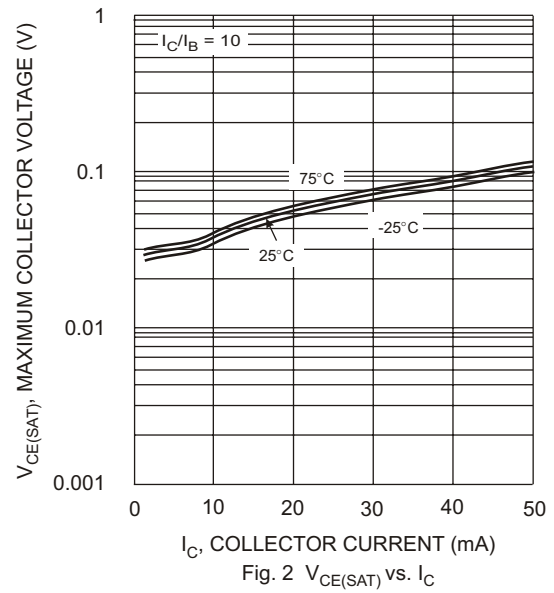


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

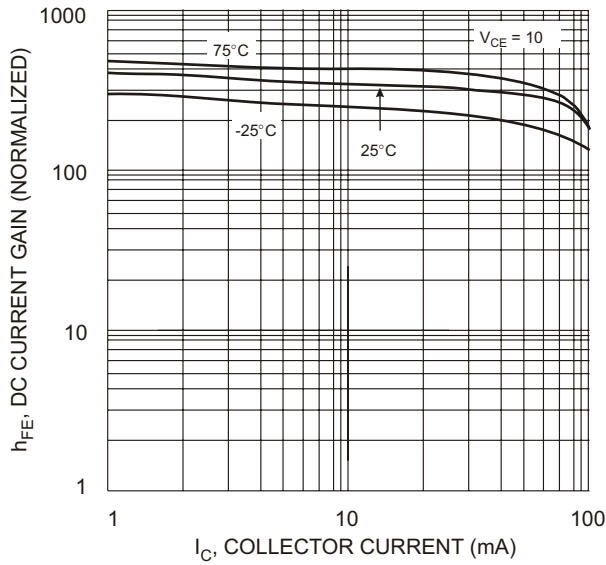


Fig. 3 DC Current Gain

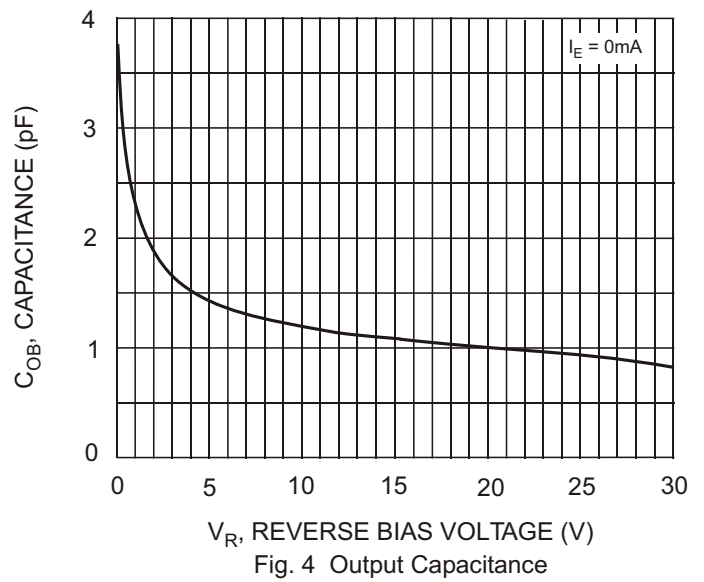


Fig. 4 Output Capacitance

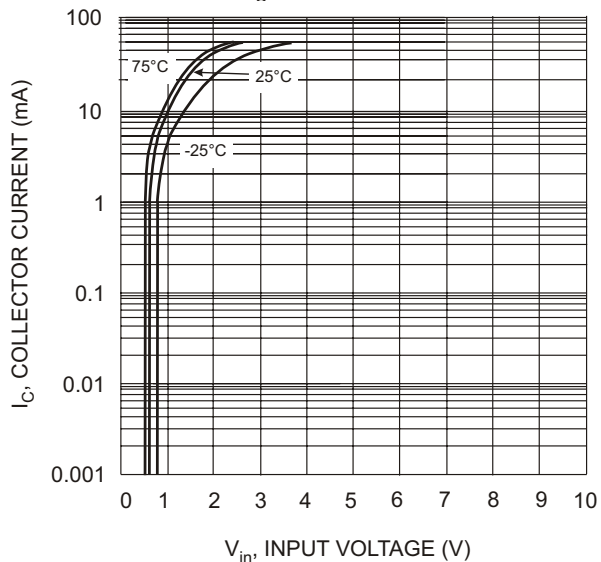


Fig. 5 Collector Current Vs. Input Voltage

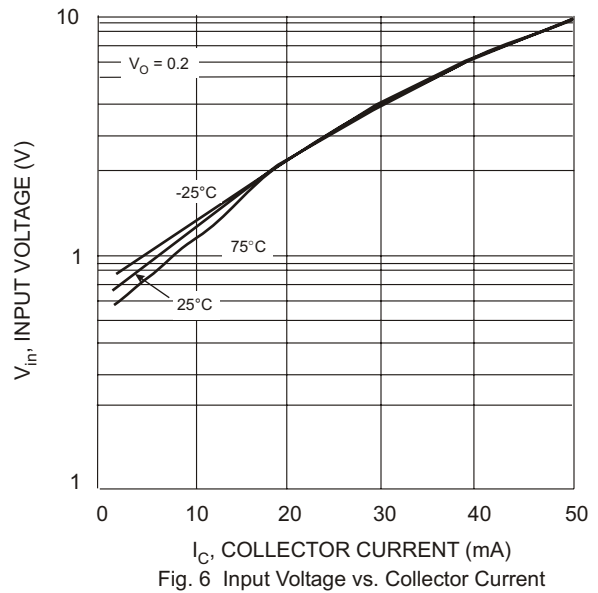


Fig. 6 Input Voltage vs. Collector Current

TYPICAL CURVES - DCX114TU

NPN SECTION

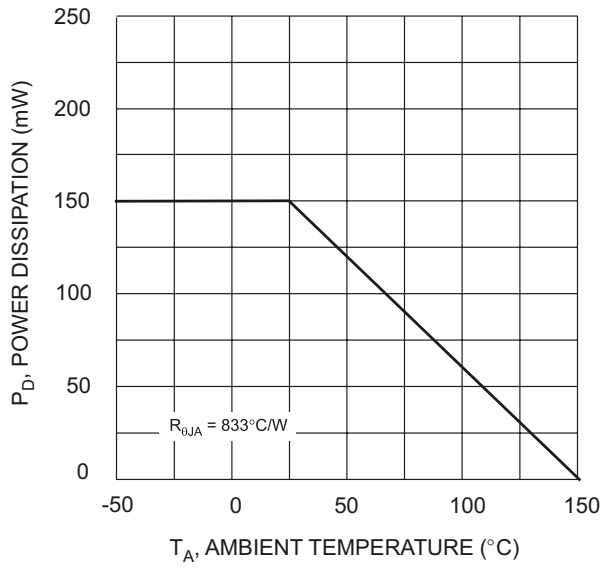


Fig. 1 Derating Curve

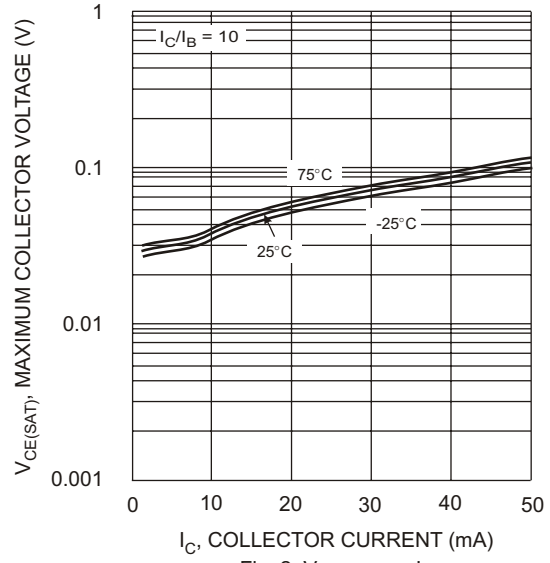


Fig. 2  $V_{CE(SAT)}$  vs.  $I_C$

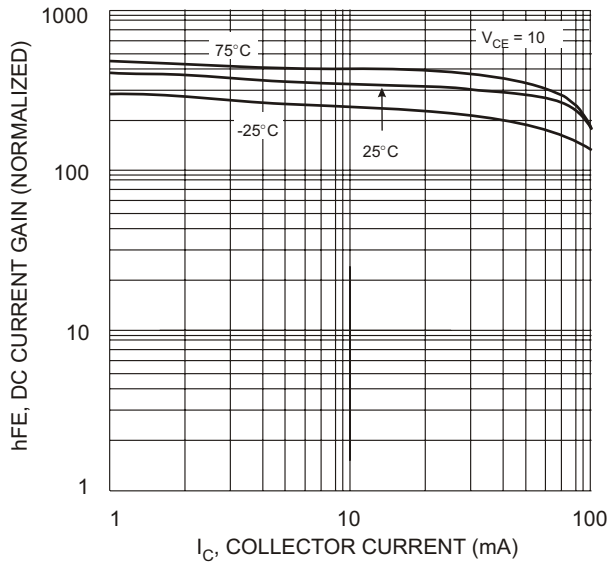


Fig. 3 DC Current Gain

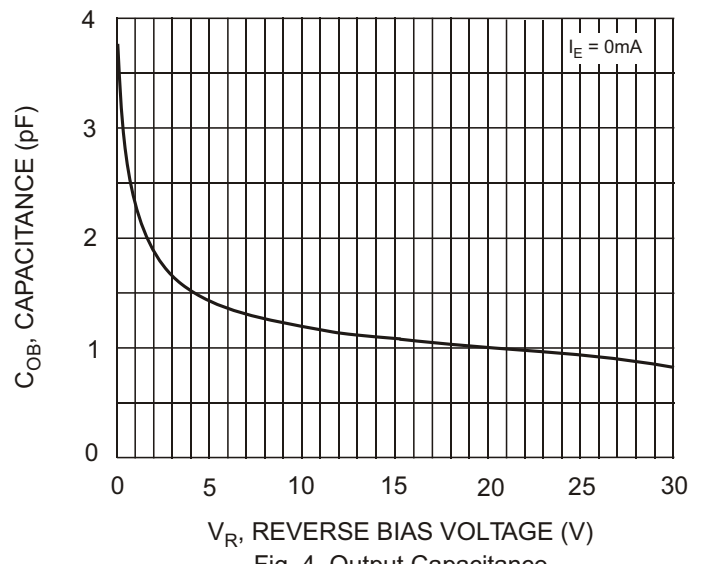


Fig. 4 Output Capacitance

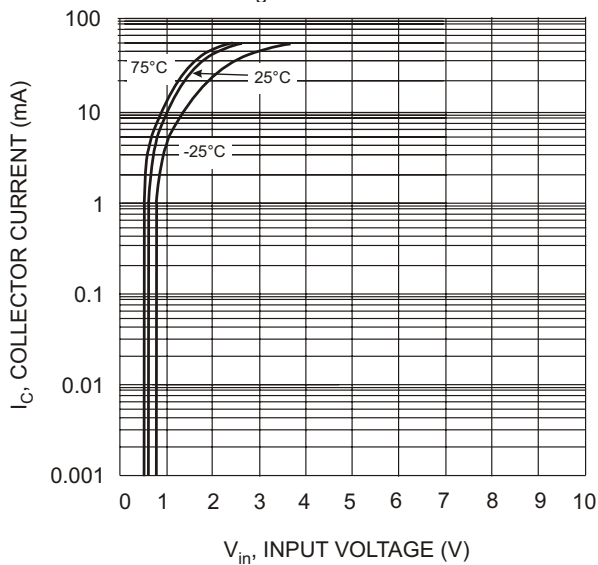


Fig. 5 Collector Current Vs. Input Voltage

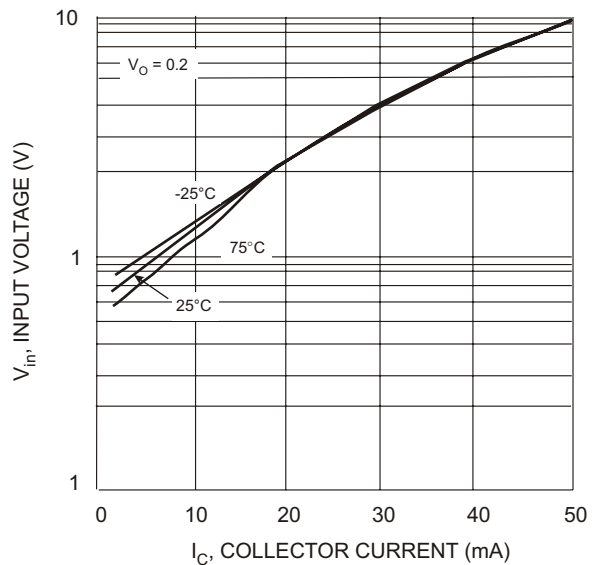


Fig. 6 Input Voltage vs. Collector Current